

ნ.მახათაძის პუბლიკაციები, პატენტები, კონფერენციებსა და საგრანტო თემებში
მონაწილეობა

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ადგილობრივ და საერთაშორისო კონფერენციებში მონაწილეობა

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გრანტის გამცემი ორგანიზაცია	წწ.	გრანტის დასახელება	პოზიცია
STCU--ს გრანტი #6204	2016-2018	ნანომავთულების გაზრდის ახალი ტექნოლოგიების შემუშავება და აირების ზემგრძობიარე სენსორების დამზადება	ძირითადი შემსრულებელი
შვეიცარიის ეროვნულ- ლი სამეცნიერო ფონ- დის გრანტი SCOPES IZ73Z0_127943 / 1	2009-2012	ერთგანზომილებიანი ნიტრიდული და ოქსიდური ნანომასალების მიღება გარემოსდაცვითი და ენერგეტიკის მიზნებისათვის	ძირითადი შემსრულებელი
სტუ-ს გამოყენებითი პროექტი #117	2011-2012	ნანოსტრუქტურული ზემგრძობიარე სენსორული არეების მიღება ტოქსიკური აირების დეტექტირებისათვის	ძირითადი შემსრულებელი